



**THE DATASHEET OF
SM8S12AHE3/2D**



Surface Mount PAR[®] Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



DO-218AB

| PRIMARY CHARACTERISTICS | |
|---------------------------------|------------------|
| V_{BR} | 11.1 V to 52.8 V |
| P_{PPM} (10 x 1000 μ s) | 6600 W |
| P_{PPM} (10 x 10 000 μ s) | 5200 W |
| P_D | 8 W |
| V_{WM} | 10 V to 43 V |
| I_{FSM} | 700 A |
| T_J max. | 175 °C |
| Polarity | Uni-directional |
| Package | DO-218AB |

FEATURES

- Junction passivation optimized design passivated anisotropic rectifier technology
- $T_J = 175$ °C capability suitable for high reliability and automotive requirement
- Available in uni-directional polarity only
- Low leakage current
- Low forward voltage drop
- High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AB

Molding compound meets UL 94 V-0 flammability rating
 Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified
 Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified
 ("X" denotes revision code e.g. A, B, ..., revision code only applicable for part number with ± 5 % tolerance)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

| MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted) | | | |
|--|-----------------|---------------------------------|------|
| PARAMETER | SYMBOL | VALUE | UNIT |
| Peak pulse power dissipation | P_{PPM} | with 10/1000 μ s waveform | 6600 |
| | | with 10/10 000 μ s waveform | 5200 |
| Power dissipation on infinite heatsink at $T_C = 25$ °C (fig. 1) | P_D | 8.0 | W |
| Peak pulse current with 10/1000 μ s waveform | $I_{PPM}^{(1)}$ | See next table | A |
| Peak forward surge current 8.3 ms single half sine-wave | I_{FSM} | 700 | A |
| Operating junction and storage temperature range | T_J, T_{STG} | -55 to +175 | °C |

Note

⁽¹⁾ Non-repetitive current pulse derated above $T_A = 25$ °C



| ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | | | | |
|--|---------------------------------------|------|----------------------------------|---------------------------------------|--|--|--|---|
| DEVICE TYPE | BREAKDOWN VOLTAGE V _{BR} (V) | | TEST CURRENT I _T (mA) | STAND-OFF VOLTAGE V _{WM} (V) | MAXIMUM REVERSE LEAKAGE AT V _{WM} I _D (μA) | MAXIMUM REVERSE LEAKAGE AT V _{WM} T _J = 175 °C I _D (μA) | MAX. PEAK PULSE CURRENT AT 10/1000 μs WAVEFORM (A) | MAXIMUM CLAMPING VOLTAGE AT I _{PPM} V _C (V) |
| | MIN. | MAX. | | | | | | |
| SM8S10 | 11.1 | 13.6 | 5.0 | 10.0 | 15 | 250 | 351 | 18.8 |
| SM8S10A | 11.1 | 12.3 | 5.0 | 10.0 | 15 | 250 | 388 | 17.0 |
| SM8S11 | 12.2 | 14.9 | 5.0 | 11.0 | 10 | 150 | 328 | 20.1 |
| SM8S11A | 12.2 | 13.5 | 5.0 | 11.0 | 10 | 150 | 363 | 18.2 |
| SM8S12 | 13.3 | 16.3 | 5.0 | 12.0 | 10 | 150 | 300 | 22.0 |
| SM8S12A | 13.3 | 14.7 | 5.0 | 12.0 | 10 | 150 | 332 | 19.9 |
| SM8S13 | 14.4 | 17.6 | 5.0 | 13.0 | 10 | 150 | 277 | 23.8 |
| SM8S13A | 14.4 | 15.9 | 5.0 | 13.0 | 10 | 150 | 307 | 21.5 |
| SM8S14 | 15.6 | 19.1 | 5.0 | 14.0 | 10 | 150 | 256 | 25.8 |
| SM8S14A | 15.6 | 17.2 | 5.0 | 14.0 | 10 | 150 | 284 | 23.2 |
| SM8S15 | 16.7 | 20.4 | 5.0 | 15.0 | 10 | 150 | 245 | 26.9 |
| SM8S15A | 16.7 | 18.5 | 5.0 | 15.0 | 10 | 150 | 270 | 24.4 |
| SM8S16 | 17.8 | 21.8 | 5.0 | 16.0 | 10 | 150 | 229 | 28.8 |
| SM8S16A | 17.8 | 19.7 | 5.0 | 16.0 | 10 | 150 | 254 | 26.0 |
| SM8S17 | 18.9 | 23.1 | 5.0 | 17.0 | 10 | 150 | 216 | 30.5 |
| SM8S17A | 18.9 | 20.9 | 5.0 | 17.0 | 10 | 150 | 239 | 27.6 |
| SM8S18 | 20.0 | 24.4 | 5.0 | 18.0 | 10 | 150 | 205 | 32.2 |
| SM8S18A | 20.0 | 22.1 | 5.0 | 18.0 | 10 | 150 | 226 | 29.2 |
| SM8S20 | 22.2 | 27.1 | 5.0 | 20.0 | 10 | 150 | 184 | 35.8 |
| SM8S20A | 22.2 | 24.5 | 5.0 | 20.0 | 10 | 150 | 204 | 32.4 |
| SM8S22 | 24.4 | 29.8 | 5.0 | 22.0 | 10 | 150 | 168 | 39.4 |
| SM8S22A | 24.4 | 26.9 | 5.0 | 22.0 | 10 | 150 | 186 | 35.5 |
| SM8S24 | 26.7 | 32.6 | 5.0 | 24.0 | 10 | 150 | 153 | 43.0 |
| SM8S24A | 26.7 | 29.5 | 5.0 | 24.0 | 10 | 150 | 170 | 38.9 |
| SM8S26 | 28.9 | 35.3 | 5.0 | 26.0 | 10 | 150 | 142 | 46.6 |
| SM8S26A | 28.9 | 31.9 | 5.0 | 26.0 | 10 | 150 | 157 | 42.1 |
| SM8S28 | 31.1 | 38.0 | 5.0 | 28.0 | 10 | 150 | 132 | 50.1 |
| SM8S28A | 31.1 | 34.4 | 5.0 | 28.0 | 10 | 150 | 145 | 45.4 |
| SM8S30 | 33.3 | 40.7 | 5.0 | 30.0 | 10 | 150 | 123 | 53.5 |
| SM8S30A | 33.3 | 36.8 | 5.0 | 30.0 | 10 | 150 | 136 | 48.4 |
| SM8S33 | 36.7 | 44.9 | 5.0 | 33.0 | 10 | 150 | 112 | 59.0 |
| SM8S33A | 36.7 | 40.6 | 5.0 | 33.0 | 10 | 150 | 124 | 53.3 |
| SM8S36 | 40.0 | 48.9 | 5.0 | 36.0 | 10 | 150 | 103 | 64.3 |
| SM8S36A | 40.0 | 44.2 | 5.0 | 36.0 | 10 | 150 | 114 | 58.1 |
| SM8S40 | 44.4 | 54.3 | 5.0 | 40 | 10 | 150 | 92.4 | 71.4 |
| SM8S40A | 44.4 | 49.1 | 5.0 | 40 | 10 | 150 | 102 | 64.5 |
| SM8S43 | 47.8 | 58.4 | 5.0 | 43 | 10 | 150 | 86 | 76.7 |
| SM8S43A | 47.8 | 52.8 | 5.0 | 43 | 10 | 150 | 95.1 | 69.4 |

Note

- For all types maximum V_F = 1.8 V at I_F = 100 A measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum



| THERMAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted) | | | |
|--|-----------------|-------|--------------------|
| PARAMETER | SYMBOL | VALUE | UNIT |
| Typical thermal resistance, junction to case | $R_{\theta JC}$ | 0.90 | $^\circ\text{C/W}$ |

| ORDERING INFORMATION (Example) | | | | |
|--------------------------------|-----------------|------------------------|---------------|---|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| SM8S10AHE3/2D ⁽¹⁾ | 2.605 | 2D | 750 | 13" diameter plastic tape and reel, anode towards the sprocket hole |
| SM8S10AHE3_A/I ⁽¹⁾ | 2.605 | I | 750 | 13" diameter plastic tape and reel, anode towards the sprocket hole |

Note

⁽¹⁾ AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

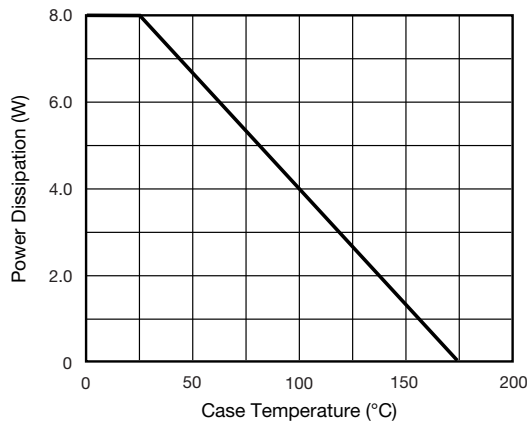


Fig. 1 - Power Derating Curve



Fig. 3 - Pulse Waveform

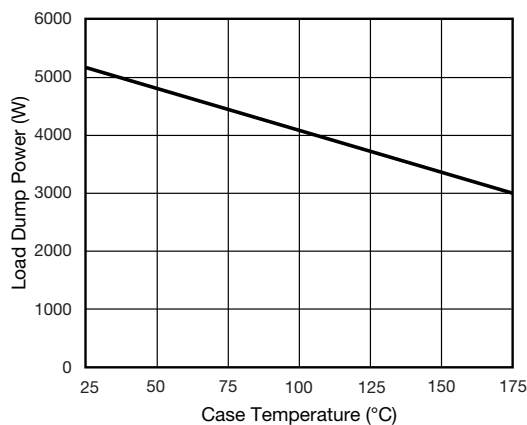


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)



Fig. 4 - Reverse Power Capability



Fig. 5 - Typical Transient Thermal Impedance



Fig. 6 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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